Optical transmission properties of C-shaped subwavelength waveguides on silicon

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Optical properties of C-shaped subwavelength waveguides in metallic (silver) films on silicon substrates are studied in the range of 0.6–6 μm. Power throughput and resonant wavelengths of several transmission modes are studied by varying the waveguide length (or metal thickness).

Among three types of transmission modes, the fundamental order of the Fabry–Perot-type mode was shown to attain remarkably high power throughputs (as high as 12). With optimized design of the aperture, the resonant wavelength of this mode occurs in the 1–2 μm wavelength range, suggesting that such apertures can be utilized to achieve plasmonic-enhanced silicon photonic devices at telecommunication wavelengths. © 2010 American Institute of Physics. [doi:10.1063/1.3455839]

Subwavelength apertures are promising candidates for many nanophotonics applications where a combination of high transmittance and subwavelength spot size is necessary. Among the possible configurations, C-shaped single apertures have certain advantages due to their compact structure, which does not require the presence of arrays or extensive corrugation. C-shaped apertures have been utilized in photodetectors, waveguides, and surface-emitting lasers. There have been a number of numerical studies addressing the transmission properties of C-shaped apertures. Most of them, however, studied free-standing or metal-semiconductor interface...
flow—related to $S_4$ and $S_5$ in the very thin (2 nm) silicon layer adjacent to the metal—is negligible. This necessary clarification also applies to the same method of calculating PT in our earlier publication.\textsuperscript{11}

The evolution of spectral response with metal film thickness is shown in Fig. 1. The response is measured at point P1 in the inset of Fig. 1. The spectrum shows three different types of modes. They include: one evanescently coupled surface plasmon (ESCP) mode (denoted as A); one thickness-invariant surface plasmon (SP) mode associated with the substrate-metal interface at the wavelength of approximately 1 $\mu$m (denoted as E); and a Fabry--Perot (FP)-type cavity mode, showing an increasing number of orders with increased thickness (denoted as B, C, and D).\textsuperscript{11}

It is apparent from Fig. 1 that the change in the resonance wavelengths of the FP mode orders, $\lambda_{FP}$, is not linear with $d$ (the FP cavity length), as might be expected for a true FP mode under ideal conditions. It must be pointed out that the wavelength of the FP resonances is determined not only by the thickness of the cavity but also by the phase change, $\phi$, upon reflection from the front and back surfaces

$$\lambda_{FP} = 2d/(N - \phi/\pi),$$

where $N$ is an integer.\textsuperscript{14} Therefore, the spectral position of the FP peaks can and does in this case differ considerably from $2d/N$.

The PT for each mode at its peak wavelength as a function of $d$ was computed (Fig. 2). The ESCP mode is clearly evanescent in nature, since its PT decays exponentially with $d$. Although the transmittance via this mode may be somewhat high (and extraordinary, PT $\sim 4$) for small metal film thicknesses, it is not suitable for telecom applications, since the peak wavelength occurs in the 3.5--4 $\mu$m wavelength range (Fig. 1). The wavelength peak for this mode is indeed in the 1--2 $\mu$m range of interest and the PT can be even higher (PT $\sim 6$) if the substrate refractive index is close to 1, i.e., a free-standing apertures.\textsuperscript{14} These observations on transmission properties of the ESCP mode in C-shaped apertures may explain the discrepancy between prediction of high PT in free-standing apertures\textsuperscript{10} and low performance of fabricated nanophotonic devices based on them (apertures on semiconductors).\textsuperscript{5}

Another interesting finding of Fig. 2 is that the PT for the SP mode oscillates versus $d$ with a nearly constant period (400 nm). Closer inspection and comparison of Figs. 1 and 2 reveals that the peaks in PT occur at the wavelengths of spectral overlap of SP and FP modes. As each successive order of the FP mode crosses the wavelength of the SP peak, both local intensity and PT of the SP mode increase sharply. Note that this same phenomenon has the opposite effect on the PT of the FP modes, i.e., it causes a sudden drop in the PT, particularly apparent at $d$=600 nm for FP2 (second order of the FP mode, open triangles in Fig. 2) and $d$=1000 nm for FP3 (open diamonds). The Poynting vector distribution at the wavelength of the FP mode acquires the symmetry characteristics of the SP, and a large fraction of power is scattered back toward the entrance surface.\textsuperscript{11} The fact that PT of the SP mode peaks during such coupling indicates that the energy flow at these crossover wavelengths may have a hybrid character.

The most noteworthy result of this study is the behavior of the PT of the first order of the FP mode (FP1) of the aperture-waveguide. As shown in Fig. 2, by manipulating the thickness of the metal layer (i.e., waveguide length), PT values of nearly 12 can be achieved. Thus, it is important to focus on this fundamental FP mode for nanophotonic applications on real substrates rather than the tempting ESCP mode which appears to have modestly high PT but only in free-standing apertures. A high extraordinary PT of 12 for FP1 is due to the light-gathering ability of the subwavelength metal structure, where the energy incident onto the metal surface is captured in the form of surface plasmon waves and “fanned” via the waveguide FP-type mode.

The origin of the peak in the PT occurring at $d$=1000 nm in Fig. 2 may be related to the phase difference in Eq. (1). That is, the PT is maximal when the incident and reflected waves in the aperture cavity are in phase with each other. As mentioned before, varying the thickness of the metal layer affects both $\lambda_{FP}$ and $\phi$ and therefore it is plausible that for a certain value of $d$ this optimal condition can be achieved. Assuming $N=1$, for the fundamental FP mode, we calculated $\phi$ for every $\lambda_{FP}$ (at each value of $d$) using Eq. (1) and found that PT indeed peaks when $\phi$ is close to zero.
(inset of Fig. 3). This finding is further supported by the spatial distribution of the PT for this mode. Figure 3 shows the normalized $z$-derivatives (through point P1) of the $z$-component of the Poynting vector, $dS_z/dz$, for five different values of $d$. This figure is intended to illustrate that for $d=1000$ nm (the thickness at which the peak in PT occurs), the spatial distribution is most uniform, i.e., $dS_z/dz \sim 0$. This is consistent with the minimal phase change upon reflection from the cavity surfaces. Furthermore, it is interesting to note that for all $d < 1000$ nm, the $S_z$ slopes toward the entrance surface, while the opposite is true for $d > 1000$.

The two higher orders of the FP mode (FP2 and FP3) show similar tendencies and may peak as $d$ is increased beyond 2500 nm. Figure 4 presents the PTs of the three FP modes as a function of peak wavelength, $\lambda_{FP}$. It is evident that although the PTs of different FP modes are different for the same waveguide lengths (see Fig. 2), the PTs show similar trends when plotted versus $\lambda_{FP}$. It is well-known that the reflectance of a FP cavity with fixed length is a periodic function of wavelength with the peaks corresponding to each successive order of the FP mode. In other words, the value of the reflectance at the peak wavelength of each FP order is the same. By increasing the cavity length (i.e., the metal film thickness) in the present case, higher FP orders can result in resonant wavelengths and hence reflectivities identical to those of the lower order(s) in thinner metal thicknesses (or shorter waveguides). Therefore, it is not surprising that the variation in the reflectance (and hence the PT) is almost the same for all three FP orders when plotted versus $\lambda_{FP}$.

A PT of $\sim 7$ is predicted for FP1 at $\lambda_{FP}=1.55$ $\mu$m wavelength of telecommunication at $d=400$ nm. Similar PTs can be achieved at the higher FP2 and FP3 orders at the same wavelength, however at the expense of $>1100$ nm and $>2000$ nm metal thicknesses, respectively. Clearly, for this aperture geometry, only the FP1 mode renders itself to nanophotonic devices when practical thicknesses related to device fabrication issues are considered. Finally, it is noted that the highest PT of $\sim 12$ is predicted in Fig. 4 for the FP1 mode at the peak wavelength of $\lambda_{FP}=1.92$ $\mu$m. Further optimization of the lateral geometry of the C-shaped nanoaperture can blueshift the PT in Fig. 4, in order to attain a maximal value in the telecommunication range of 1.3–1.55 $\mu$m.

In summary, this study shows that even under the conditions of refractive index mismatch between the aperture cavity and the substrate, high PT values can be achieved in C-shaped subwavelength aperture-waveguides in near-infrared wavelengths. For this purpose it is not only necessary to optimize the design of the aperture (both shape and thickness) but to also emphasize the FP-type modes.

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